



SANYO Semiconductors

DATA SHEET

LV5609V — Bi-CMOS LSI For CCD Vertical Clock Driver

Overview

The LV5609V is vertical clock driver for CCD.

Functions

- Ternary output ×2ch
- Binary output ×2ch
- SHT output ×1ch
- Output ON resistance : 30Ω typ

Specifications

Absolute Maximum Ratings at Ta = 25°C, VSS = VM = 0V

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{DD} max		6	V
	V _H max		20	V
	V _L max		-10	V
	V _H -V _L max		24	V
Allowable power dissipation	P _d max	with specified substrate *	0.67	W
Operating temperature	T _{opr}		-20 to +80	°C
Storage temperature	T _{stg}		-40 to +125	°C

* : Specified substrate : 114.3×76.1×1.6mm³, glass epoxy board

Allowable Operating Ratings at Ta = 25°C, VSS = VM = 0V

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Supply voltage	V _{DD}		2.0	3.3	5.5	V
	V _H			15	17	V
	V _L		-8.5	-7.5	-4	V
	V _H -V _L				23.5	V
CMOS input High voltage	V _{INH}		0.8V _{DD}		V _{DD}	V
CMOS input Low voltage	V _{INL}		-0.1		0.4	V

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SANYO Semiconductor Co., Ltd.

TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

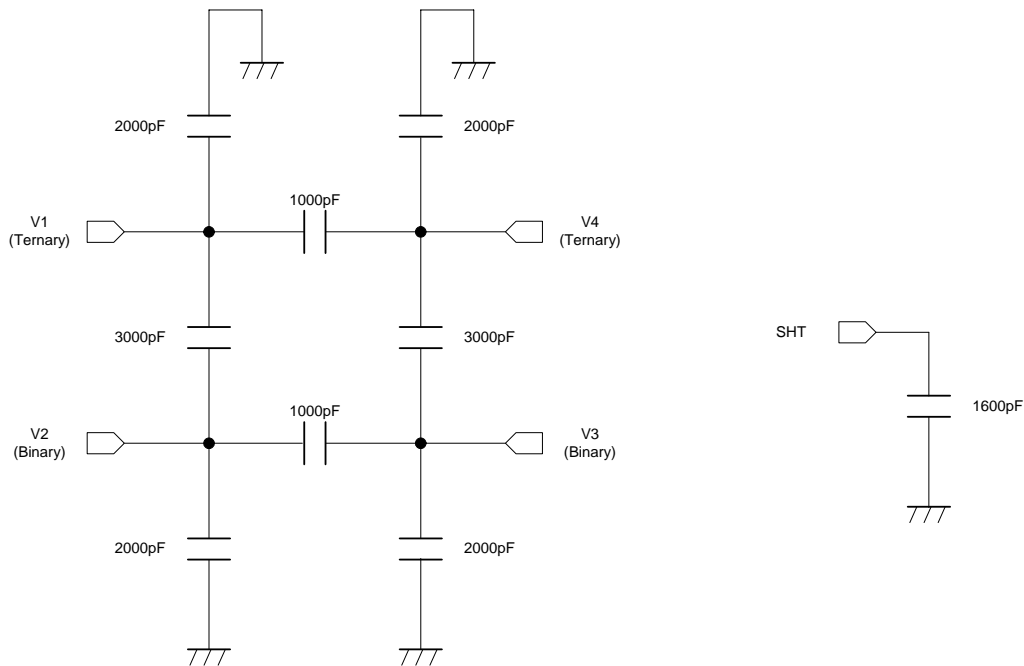
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Electrical Characteristics at $T_a = 25^\circ\text{C}$, $V_{DD} = 3.3\text{V}$, $V_{SS} = 0\text{V}$, $V_H = 15\text{V}$, $V_L = -7.5\text{V}$, $V_M = 0\text{V}$,
Unless otherwise specified

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Static current drain	I_{DD}	V_{DD} pin			1	μA
	I_H	V_H pin			10	μA
	I_L	V_L pin			1	μA
Dynamic current drain	I_{DD}	V_{DD} pin See *1 and *2.			1	mA
	I_H	V_H pin See *1 and *2.		2.4	4.5	mA
	I_L	V_L pin See *1 and *2.		3	5	mA
Output ON resistance	R_L	$I_O = +10\text{mA}$		20	30	Ω
	R_M	$I_O = \pm 10\text{mA}$		30	45	Ω
	R_H	$I_O = -10\text{mA}$		30	40	Ω
	R_{SHT}	$I_O = -10\text{mA}$		30	40	Ω
Propagation delay time	TPLM	No load			200	ns
	TPMH	No load			200	ns
	TPLH	No load			200	ns
	TPML	No load			200	ns
	TPHM	No load			200	ns
	TPHL	No load			200	ns
Rise time	TTLM	$V_L \rightarrow V_M$ V1, V3 See *1.			800	ns
		$V_L \rightarrow V_M$ V2, V4 See *1.			800	ns
	TTMH	$V_M \rightarrow V_L$ V1, V3 See *1.			800	ns
	TTLH	$V_L \rightarrow V_H$ SHT See *1.			200	ns
Fall time	TTML	$V_M \rightarrow V_L$ V1, V3 See *1.			800	ns
		$V_M \rightarrow V_L$ V2, V4 See *1.			800	ns
	TTHM	$V_H \rightarrow V_M$ V1, V3 See *1.			800	ns
	TTHL	$V_H \rightarrow V_L$ SHT See *1.			200	ns

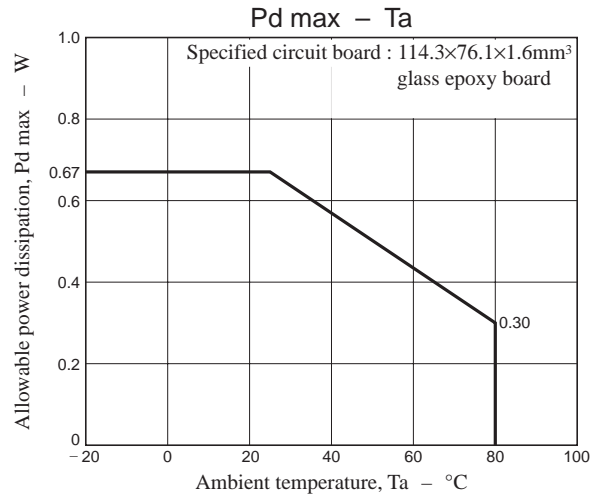
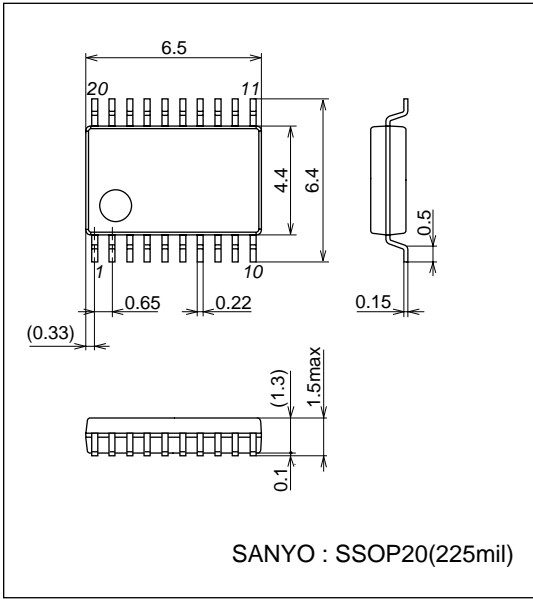
*1 : Refer to the CCD equivalent load shown below.

*2 : Refer to the timing waveform on Page 7.



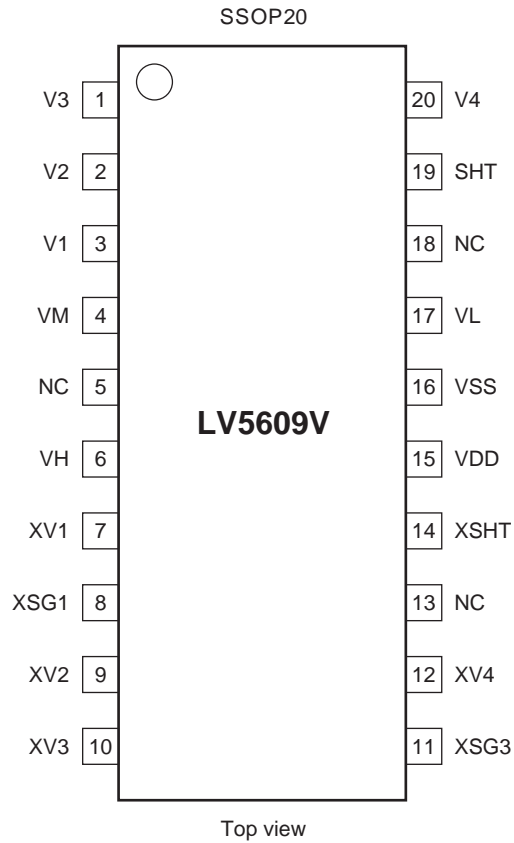
Package Dimensions

unit : mm (typ)
3179C



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Pin Assignment

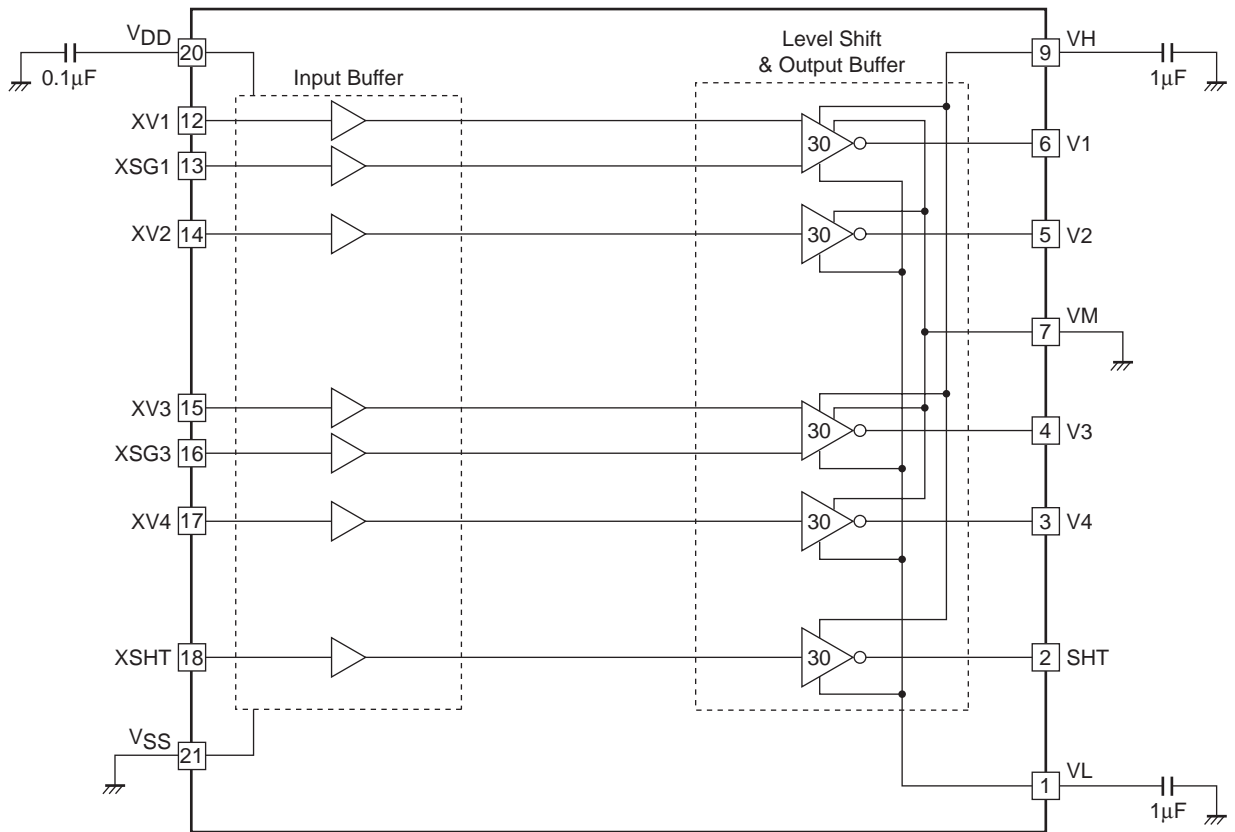


Pin Function

Pin No.	Name	Mode
1	V3	Level shift output (ternary VH, VM, VL)
2	V2	Level shift output (binary VM, VL)
3	V1	Level shift output (ternary VH, VM, VL)
4	VM	GND for output
5	NC	
6	VH	Hi power supply (15V system) for output
7	XV1	V1 transfer pulse input
8	XSG1	V1 read pulse input
9	XV2	V2 transfer pulse input
10	XV3	V3 transfer pulse input
11	XSG3	V3 read pulse input
12	XV4	V4 transfer pulse input
13	NC1	
14	XSHT	SHT pulse input
15	V _{DD}	Power supply (3.3V system) for input buffer
16	V _{SS}	GND for input buffer
17	VL	LO power supply (-7.5V system) for output
18	NC	
19	SHT	Level shift output (binary VH, VL)
20	V4	Level shift output (ternary VM, VL)

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Block Diagram

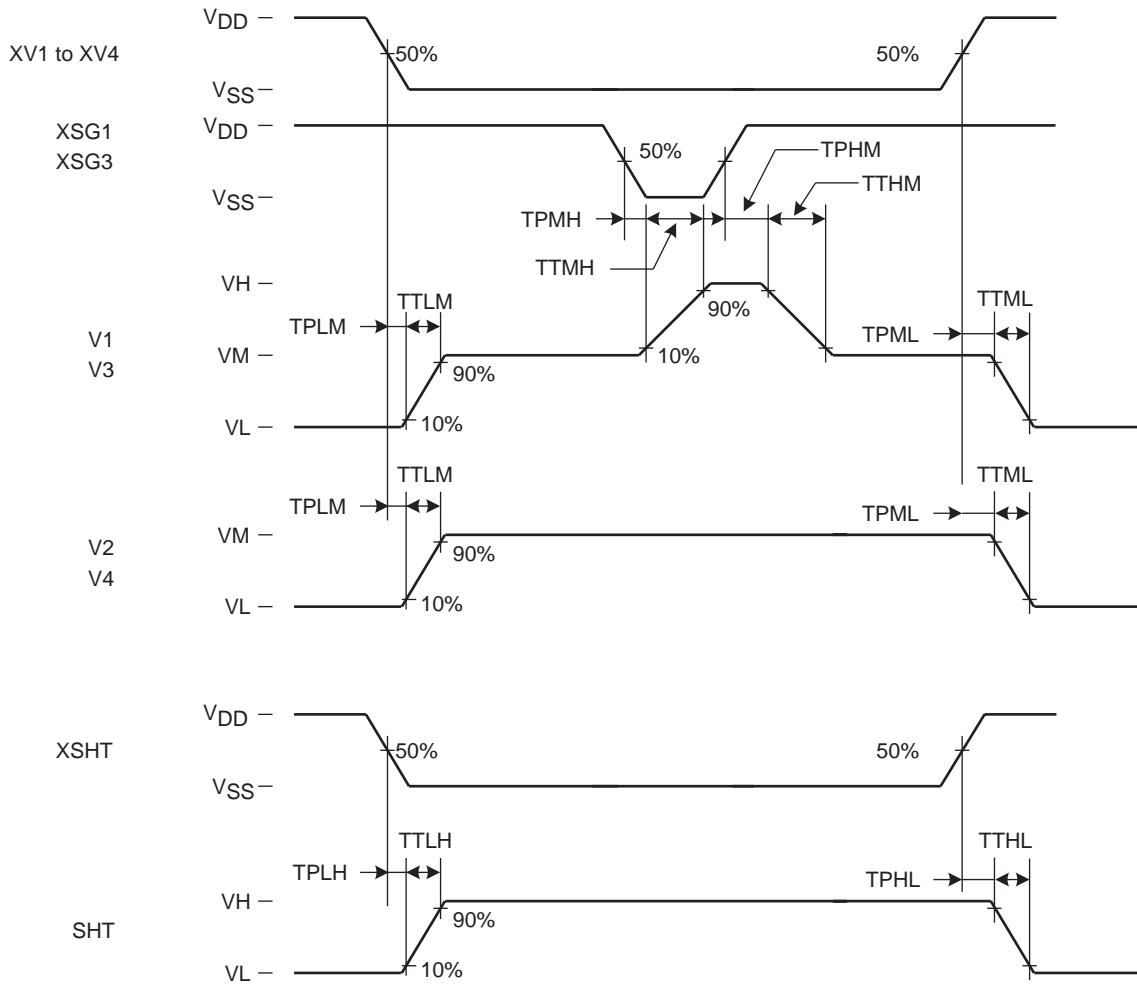


Logical Function Table

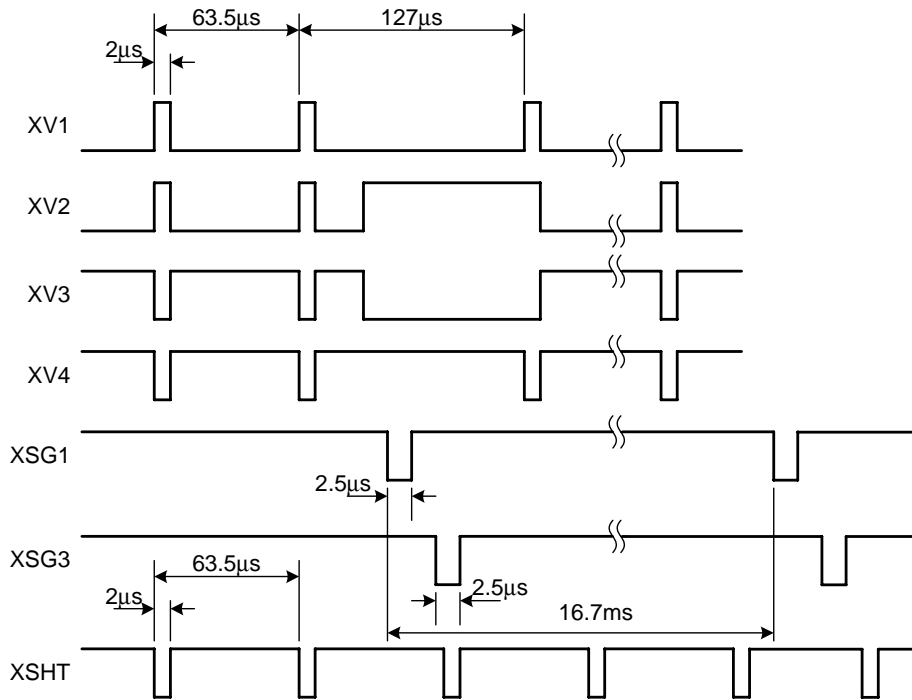
Input				Output		
XV1 XV3	XSG1 XSG3	XV2 XV4	XSHT	V1 V3	V2 V4	SHT
L	L	X	X	VH	X	X
L	H	X	X	VM	X	X
H	L	X	X	VL	X	X
H	H	X	X	VL	X	X
X	X	L	X	X	VM	X
X	X	H	X	X	VL	X
X	X	X	L	X	X	VH
X	X	X	H	X	X	VL

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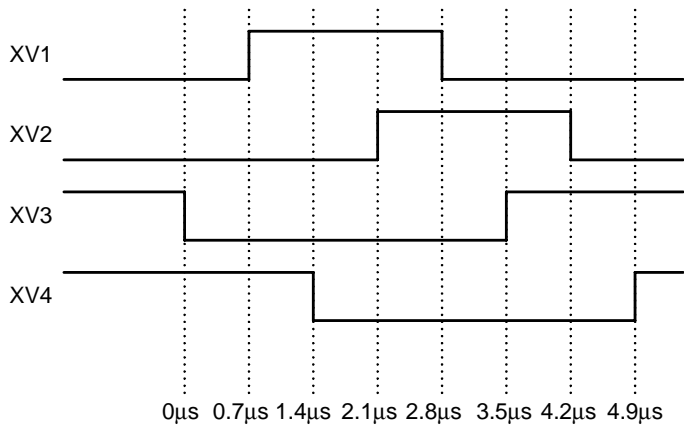
Timing Chart



CCD Equivalent Load Measurement Timing Waveform



Enlarged View of overlapped portion



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